



April 1999

FDN361AN

N-Channel, Logic Level, PowerTrench™

General Description

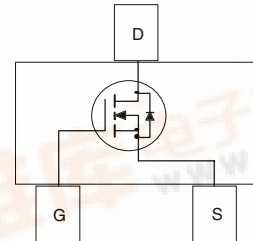
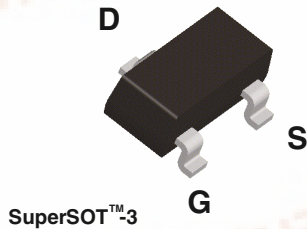
This N-Channel Logic Level MOSFET is produced using Fairchild Semiconductor's PowerTrench process that has been especially tailored to minimize the on-state resistance and yet maintain low gate charge for superior switching performance.

Applications

- DC/DC converter
- Load switch
- Motor drives

Features

- 1.8 A, 30 V. $R_{DS(on)} = 0.100 \Omega @ V_{GS} = 10 V$
 $R_{DS(on)} = 0.150 \Omega @ V_{GS} = 4.5 V.$
- Low gate charge (2.1nC typical).
- Fast switching speed.
- High performance trench technology for extremely low $R_{DS(on)}$.
- High power version of industry standard SOT-23 package. Identical pin out to SOT-23 with 30% higher power handling capability.



Absolute Maximum Ratings T_A=25°C unless otherwise noted

| Symbol | Parameter | FDN361AN | Units |
|-----------------------------------|---|-------------|-------|
| V _{DSS} | Drain-Source Voltage | 30 | V |
| V _{GSS} | Gate-Source Voltage - Continuous | ±20 | V |
| I _D | Drain Current - Continuous (Note 1a) | 1.8 | A |
| | - Pulsed | 8 | |
| P _D | Power Dissipation for Single Operation (Note 1a) (Note 1b) | 0.5 | W |
| | | 0.46 | |
| T _J , T _{stg} | Operating and Storage Junction Temperature Range | -55 to +150 | °C |

Thermal Characteristics

| | | | |
|------------------|---|-----|------|
| R _{θJA} | Thermal Resistance, Junction-to-Ambient (Note 1a) | 250 | °C/W |
| R _{θJC} | Thermal Resistance, Junction-to-Case (Note 1) | 75 | °C/W |

Package Marking and Ordering Information

| Device Marking | Device | Reel Size | Tape width | Quantity |
|----------------|----------|-----------|------------|------------|
| 361 | FDN361AN | 7" | 8mm | 3000 units |



DMOS Electrical Characteristics

$T_A = 25^\circ\text{C}$ unless otherwise noted

| Symbol | Parameter | Test Conditions | Min | Typ | Max | Units |
|--------|-----------|-----------------|-----|-----|-----|-------|
|--------|-----------|-----------------|-----|-----|-----|-------|

Off Characteristics

| | | | | | | |
|---------------------------------------|---|---|----|----|------|----------------------------|
| BV_{DSS} | Drain-Source Breakdown Voltage | $V_{GS} = 0\text{ V}, I_D = 250\ \mu\text{A}$ | 30 | | | V |
| $-\frac{\Delta BV_{DSS}}{\Delta T_J}$ | Breakdown Voltage Temperature Coefficient | $I_D = 250\ \mu\text{A}$, Referenced to 25°C | | 24 | | $\text{mV}/^\circ\text{C}$ |
| I_{DSS} | Zero Gate Voltage Drain Current | $V_{DS} = 24\text{ V}, V_{GS} = 0\text{ V}$ | | | 1 | μA |
| I_{GSSF} | Gate-Body Leakage, Forward | $V_{GS} = 20\text{ V}, V_{DS} = 0\text{ V}$ | | | 100 | nA |
| I_{GSSR} | Gate-Body Leakage, Reverse | $V_{GS} = -20\text{ V}, V_{DS} = 0\text{ V}$ | | | -100 | nA |

On Characteristics (Note 2)

| | | | | | | |
|--|--|--|---|-------------------------|---------------------|----------------------------|
| $V_{GS(th)}$ | Gate Threshold Voltage | $V_{DS} = V_{GS}, I_D = 250\ \mu\text{A}$ | 1 | 1.8 | 3 | V |
| $\frac{\Delta V_{GS(th)}}{\Delta T_J}$ | Gate Threshold Voltage Temperature Coefficient | $I_D = 250\ \mu\text{A}$, Referenced to 25°C | | -4.2 | | $\text{mV}/^\circ\text{C}$ |
| $R_{DS(on)}$ | Static Drain-Source On-Resistance | $V_{GS} = 10\text{ V}, I_D = 1.8\text{ A}$ $V_{GS} = 10\text{ V}, I_D = 1.8\text{ A}, T_J = 125^\circ\text{C}$ $V_{GS} = 4.5\text{ V}, I_D = 1.4\text{ A}$ | | 0.072 0.107 0.105 | 0.1 0.16 0.15 | Ω |
| $I_{D(on)}$ | On-State Drain Current | $V_{GS} = 10\text{ V}, V_{DS} = 5\text{ V}$ | 8 | | | A |
| g_{FS} | Forward Transconductance | $V_{DS} = 10\text{ V}, I_D = 1.8\text{ A}$ | | 5 | | S |

Dynamic Characteristics

| | | | | | | |
|-----------|------------------------------|---|--|-----|--|----|
| C_{iss} | Input Capacitance | $V_{DS} = 15\text{ V}, V_{GS} = 0\text{ V}, f = 1.0\text{ MHz}$ | | 220 | | pF |
| C_{oss} | Output Capacitance | | | 50 | | pF |
| C_{rss} | Reverse Transfer Capacitance | | | 20 | | pF |

Switching Characteristics (Note 2)

| | | | | | | |
|--------------|---------------------|--|--|-----|----|----|
| $t_{d(on)}$ | Turn-On Delay Time | $V_{DD} = 15\text{ V}, I_D = 1\text{ A},$ $V_{GS} = 10\text{ V}, R_{GEN} = 6.0\ \Omega$ | | 3 | 6 | ns |
| t | Turn-On Rise Time | | | 11 | 22 | ns |
| $t_{d(off)}$ | Turn-Off Delay Time | $V_{DS} = 15\text{ V}, I_D = 1.8\text{ A},$ $V_{GS} = 5\text{ V}$ | | 7 | 14 | ns |
| t_f | Turn-Off Fall Time | | | 3 | 6 | ns |
| Q_g | Total Gate Charge | $V_{DS} = 15\text{ V}, I_D = 1.8\text{ A},$ $V_{GS} = 5\text{ V}$ | | 2.1 | 4 | nC |
| Q_{gs} | Gate-Source Charge | | | 0.8 | | nC |
| Q_{gd} | Gate-Drain Charge | | | 0.7 | | nC |

Drain-Source Diode Characteristics and Maximum Ratings

| | | | | | | |
|----------|---|---|--|------|-----|---|
| I_S | Maximum Continuous Drain-Source Diode Forward Current | | | 0.42 | A | |
| V_{SD} | Drain-Source Diode Forward Voltage | $V_{GS} = 0\text{ V}, I_S = 0.42\text{ A}$ (Note 2) | | 0.75 | 1.2 | V |

Notes:

- $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta JC}$ is guaranteed by design while $R_{\theta JA}$ is determined by the user's board design.



a) $250^\circ\text{C}/\text{W}$ when mounted on a 0.02 in^2 pad of 2 oz. Cu.



b) $270^\circ\text{C}/\text{W}$ when mounted on a minimum pad.

Scale 1 : 1 on letter size paper

- Pulse Test: Pulse Width $\leq 300\ \mu\text{s}$, Duty Cycle $\leq 2.0\%$

Typical Characteristics (continued)

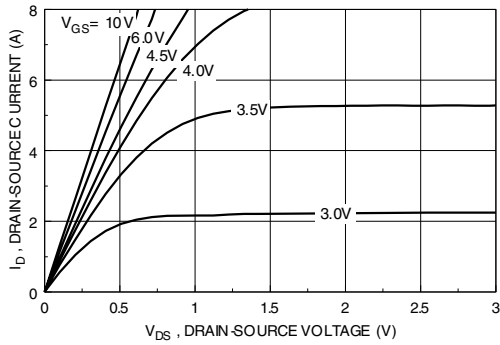


Figure 1. On-Region Characteristics.

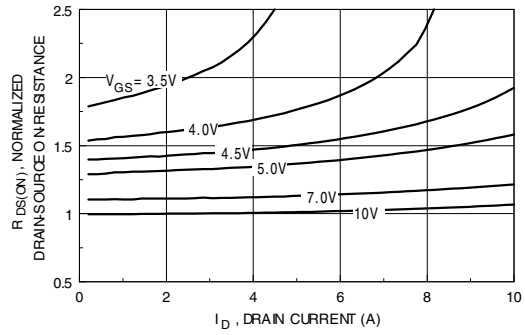


Figure 2. On-Resistance Variation with Drain Current and Gate Voltage.

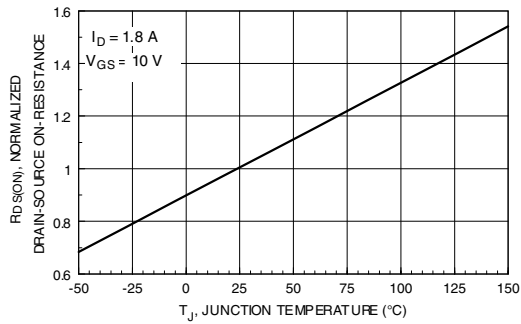


Figure 3. On-Resistance Variation with Temperature.

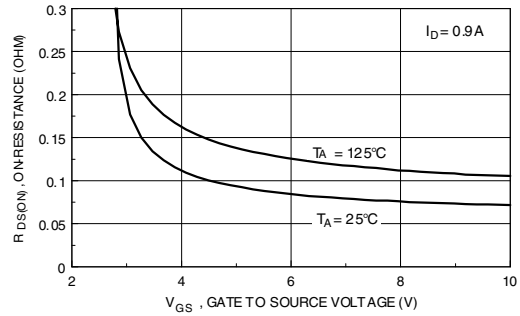


Figure 4. On-Resistance Variation with Gate-to-Source Voltage.

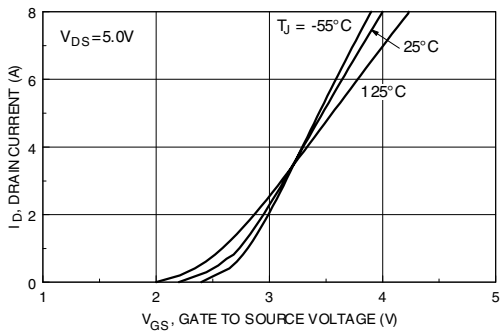


Figure 5. Transfer Characteristics.

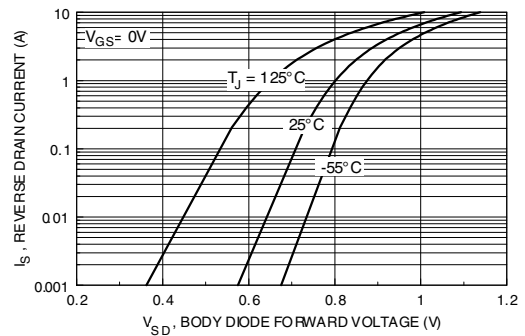


Figure 6. Body Diode Forward Voltage Variation with Source Current and Temperature.

Typical Characteristics (continued)

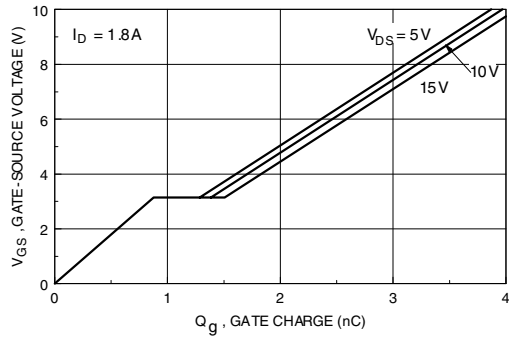


Figure 7. Gate-Charge Characteristics.

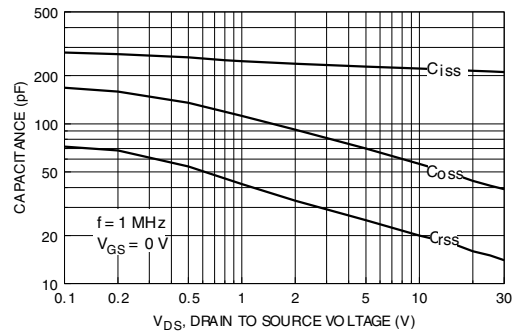


Figure 8. Capacitance Characteristics.

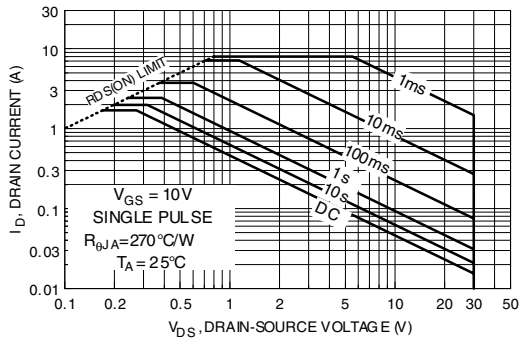


Figure 9. Maximum Safe Operating Area.

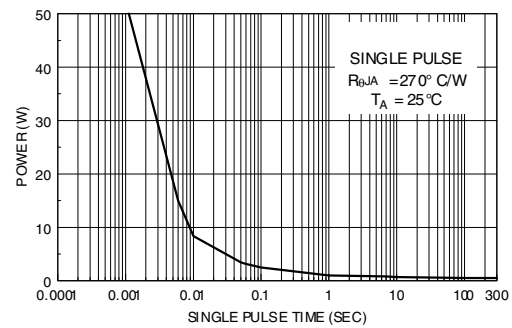


Figure 10. Single Pulse Maximum Power Dissipation.

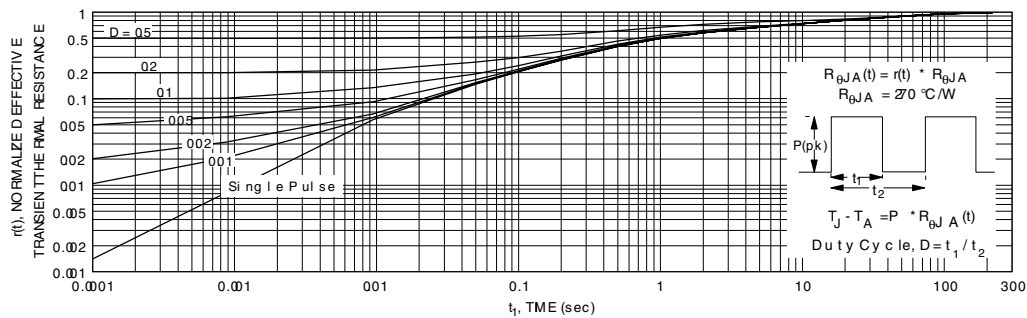


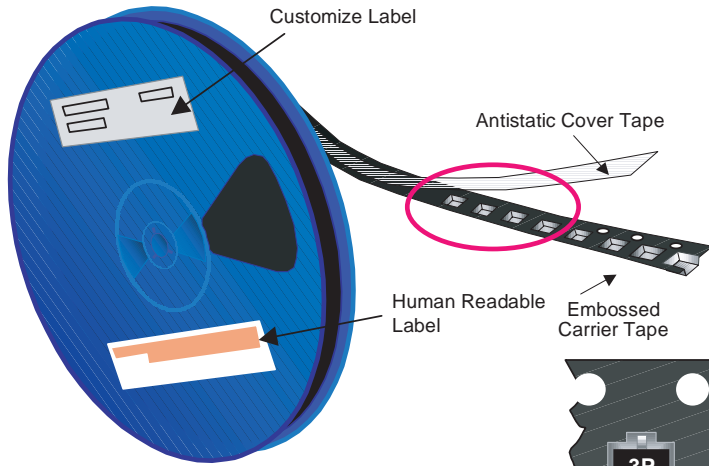
Figure 11. Transient Thermal Response Curve.

Thermal characterization performed using the conditions described in Note 1b. Transient thermal response will change depending on the circuit board design.

SuperSOT™-3 Tape and Reel Data and Package Dimensions



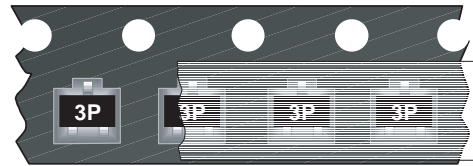
SSOT-3 Packaging Configuration: Figure 1.0



Packaging Description:

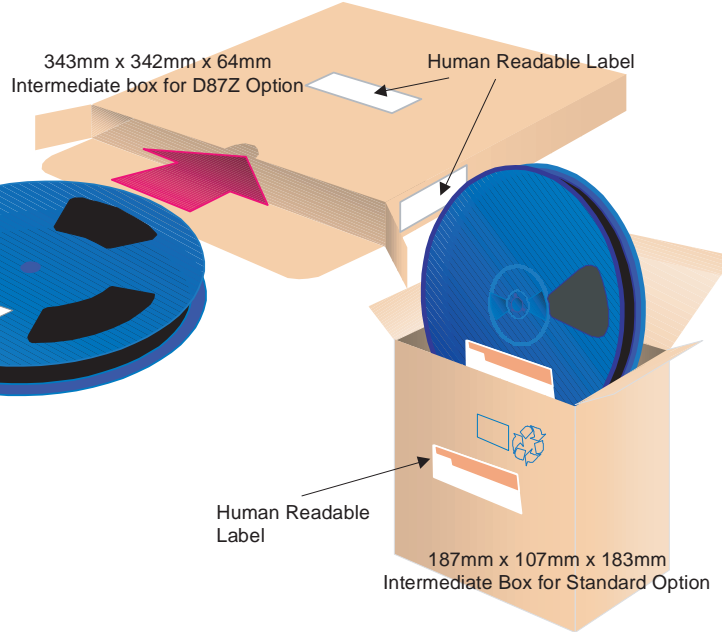
SSOT-3 parts are shipped in tape. The carrier tape is made from a dissipative (carbon filled) polycarbonate resin. The cover tape is a multilayer film (Heat Activated Adhesive in nature) primarily composed of polyester film, adhesive layer, sealant, and anti-static sprayed agent. These reeled parts in standard option are shipped with 3,000 units per 7" or 177cm diameter reel. The reels are dark blue in color and is made of polystyrene plastic (anti-static coated). Other option comes in 10,000 units per 13" or 330cm diameter reel. This and some other options are described in the Packaging Information table.

These full reels are individually labeled and placed inside a standard intermediate made of recyclable corrugated brown paper with a Fairchild logo printing. One pizza box contains eight reels maximum. And these intermediate boxes are placed inside a labeled shipping box which comes in different sizes depending on the number of parts shipped.



| SSOT-3 Std Packaging Information | | |
|----------------------------------|-------------------------|------------|
| Packaging Option | Standard (no flow code) | D87Z |
| Packaging type | TNR | TNR |
| Qty per Reel/Tube/Bag | 3,000 | 10,000 |
| Reel Size | 7" Dia | 13" |
| Box Dimension (mm) | 187x107x183 | 343x343x64 |
| Max qty per Box | 24,000 | 30,000 |
| Weight per unit (gm) | 0.0097 | 0.0097 |
| Weight per Reel (kg) | 0.1230 | 0.4150 |
| Note/Comments | | |

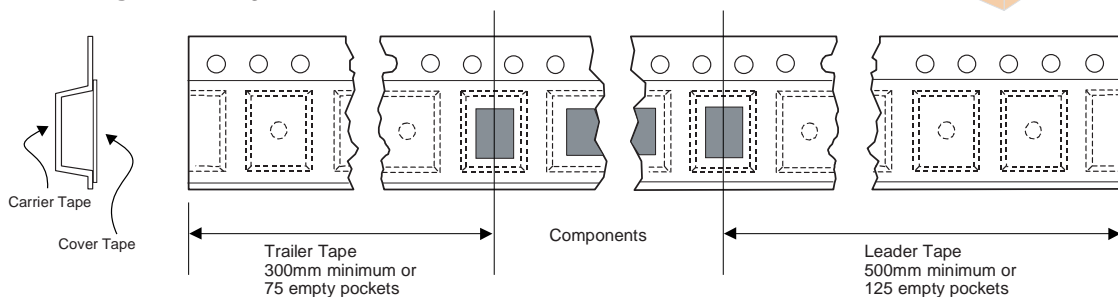
SSOT-3 Std Unit Orientation



Human Readable Label sample

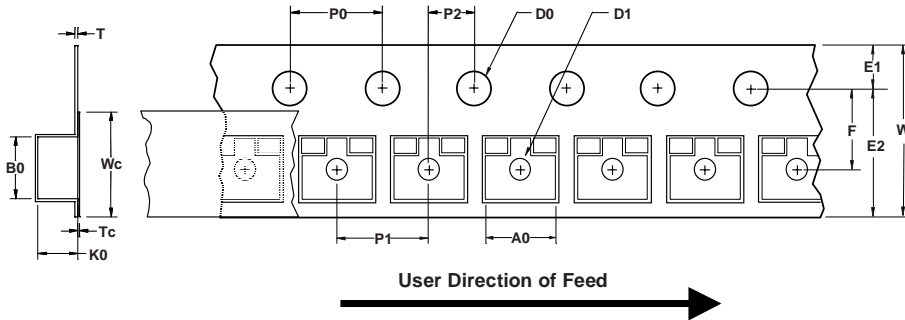


SSOT-3 Tape Leader and Trailer Configuration: Figure 2.0



SuperSOT™-3 Tape and Reel Data and Package Dimensions, continued

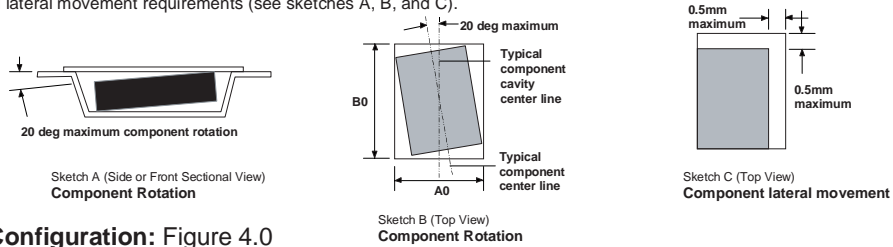
SSOT-3 Embossed Carrier Tape Configuration: Figure 3.0



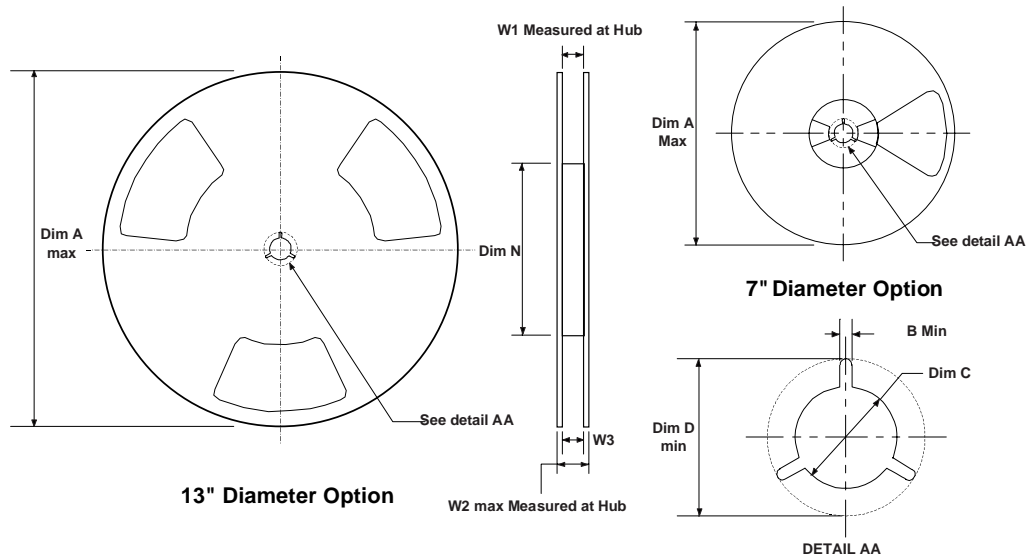
Dimensions are in millimeter

| Pkg type | A0 | B0 | W | D0 | D1 | E1 | E2 | F | P1 | P0 | K0 | T | Wc | Tc |
|--------------|-----------------|-----------------|---------------|-----------------|-------------------|-----------------|-------------|-----------------|---------------|---------------|-----------------|-------------------|---------------|-----------------|
| SSOT-3 (8mm) | 3.15 +/-0.10 | 2.77 +/-0.10 | 8.0 +/-0.3 | 1.55 +/-0.05 | 1.125 +/-0.125 | 1.75 +/-0.10 | 6.25 min | 3.50 +/-0.05 | 4.0 +/-0.1 | 4.0 +/-0.1 | 1.30 +/-0.10 | 0.228 +/-0.013 | 5.2 +/-0.3 | 0.06 +/-0.02 |

Notes: A0, B0, and K0 dimensions are determined with respect to the EIA/Jedec RS-481 rotational and lateral movement requirements (see sketches A, B, and C).



SSOT-3 Reel Configuration: Figure 4.0

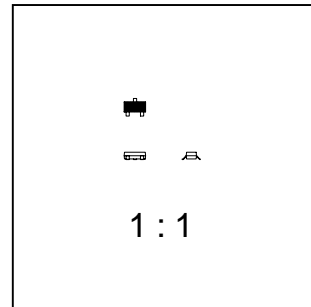
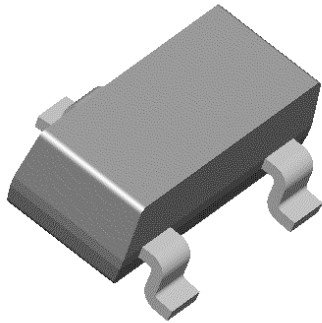


Dimensions are in inches and millimeters

| Tape Size | Reel Option | Dim A | Dim B | Dim C | Dim D | Dim N | Dim W1 | Dim W2 | Dim W3 (LSL-USL) |
|-----------|-------------|---------------|--------------|-----------------------------------|---------------|-------------|-----------------------------------|---------------|-----------------------------|
| 8mm | 7" Dia | 7.00 177.8 | 0.059 1.5 | 512 +0.020/-0.008 13 +0.5/-0.2 | 0.795 20.2 | 2.165 55 | 0.331 +0.059/-0.000 8.4 +1.5/0 | 0.567 14.4 | 0.311 - 0.429 7.9 - 10.9 |
| 8mm | 13" Dia | 13.00 330 | 0.059 1.5 | 512 +0.020/-0.008 13 +0.5/-0.2 | 0.795 20.2 | 4.00 100 | 0.331 +0.059/-0.000 8.4 +1.5/0 | 0.567 14.4 | 0.311 - 0.429 7.9 - 10.9 |

SuperSOT™-3 Tape and Reel Data and Package Dimensions, continued

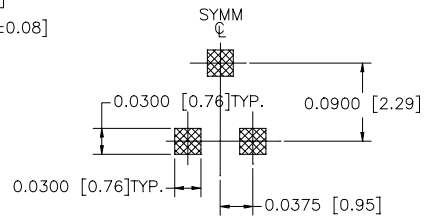
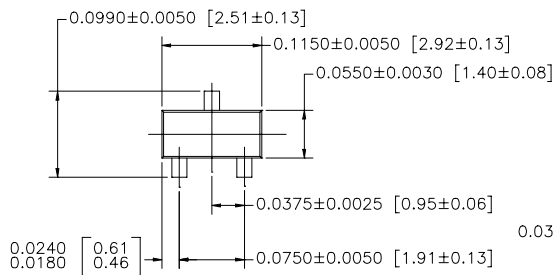
SuperSOT™-3 (FS PKG Code 32)



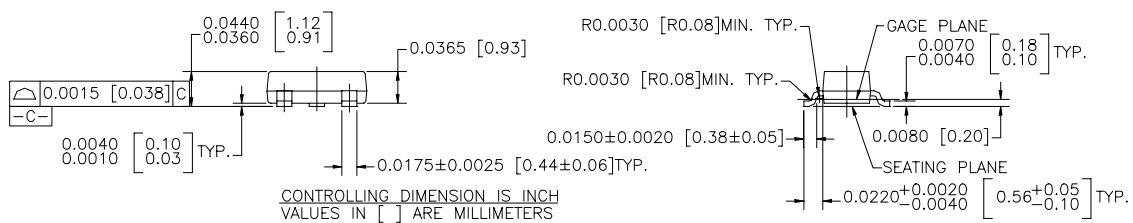
Scale 1:1 on letter size paper

Dimensions shown below are in:
inches [millimeters]

Part Weight per unit (gram): 0.0097



LAND PATTERN RECOMMENDATION



NOTES : UNLESS OTHERWISE SPECIFIED

SUPER SOT , 3 LEADS

- STANDARD LEAD FINISH TO BE 150 MICROINCHES / 3.81 MICROMETERS
MINIMUM TIN/LEAD (SOLDER) ON COPPER.
- NO JEDEC REGISTRATION AS OF DEC. 1995.

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| CoolFET™ | MICROWIRE™ | TinyLogic™ |
| CROSSVOLT™ | POP™ | UHC™ |
| E ² C MOS™ | PowerTrench® | VCX™ |
| FACT™ | QFET™ | |
| FACT Quiet Series™ | QS™ | |
| FAST® | Quiet Series™ | |
| FASTr™ | SuperSOT ¹⁰ | |
| GTO™ | SuperSOT ¹⁶ | |
| HiSeC™ | SuperSOT ¹⁸ | |

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